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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

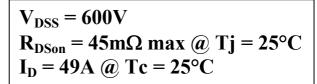


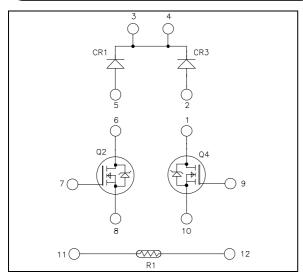


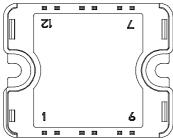




Dual boost chopper Super Junction MOSFET Power Module







Pins 3/4 must be shorted together

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction (PFC)
- Interleaved PFC

Features

COOLMOS

- Ultra low R_{DSon}
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Each leg can be easily paralleled to achieve a single boost of twice the current capability
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		600	V
т	Continuous Drain Current	$T_c = 25$ °C	49	
I_D	Continuous Diani Current	$T_c = 80^{\circ}C$	38	Α
I_{DM}	Pulsed Drain current		130	
V_{GS}	Gate - Source Voltage		±20	V
R _{DSon}	Drain - Source ON Resistance		45	mΩ
P_{D}	Maximum Power Dissipation	250	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		15	Α
E _{AR}	Repetitive Avalanche Energy		3	mJ
E_{AS}	Single Pulse Avalanche Energy		1900	1111

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$ $T_j = 25^{\circ}C$			250	μА
		$V_{GS} = 0V, V_{DS} = 600V$ $T_j = 125^{\circ}C$			500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 24.5A$		40	45	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 3mA$	2.1	3	3.9	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V ; V_{DS} = 25V$		7.2		nF
C_{oss}	Output Capacitance	f = 1MHz		8.5		Ш
Q_{g}	Total gate Charge	$V_{GS} = 10V$		150		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 300V$		34		nC
Q_{gd}	Gate – Drain Charge	$I_D = 49A$		51		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		21		
$T_{\rm r}$	Rise Time	$V_{GS} = 10V$		30		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{D}} = 49A$		100		ns
T_{f}	Fall Time	$R_G = 5\Omega$		45		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 10V$; $V_{Bus} = 400V$		675		μJ
E_{off}	Turn-off Switching Energy	$I_D = 49A$; $R_G = 5\Omega$		520		μυ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1100		1
E _{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 49A ; R_G = 5\Omega$		635		μJ

Chopper diode ratings and characteristics Symbol Characteristic T

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
Ţ	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25$ °C			25	^
I_{RM}		v _R -000 v	$T_j = 125$ °C			500	μA
I_F	DC Forward Current		Tc = 80°C		60		A
	Diode Forward Voltage	$I_F = 60A$			1.7	2.3	
$V_{\rm F}$		$I_F = 120A$			2		V
		$I_F = 60A$	$T_j = 125$ °C		1.4		
+	Reverse Recovery Time	$I_F = 60A$ $V_R = 400V$	$T_j = 25$ °C		70		ne
t_{rr}			$T_j = 125$ °C		140		ns
Q _{rr}	Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 25$ °C		100		пC
			$T_{j} = 125^{\circ}C$		690		110



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Linction to Case Thermal Resistance	CoolM	OS			0.5	°C/W
KthJC		Choppe	er Diode			0.85	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2	·	3	N.m
Wt	Package Weight					80	g

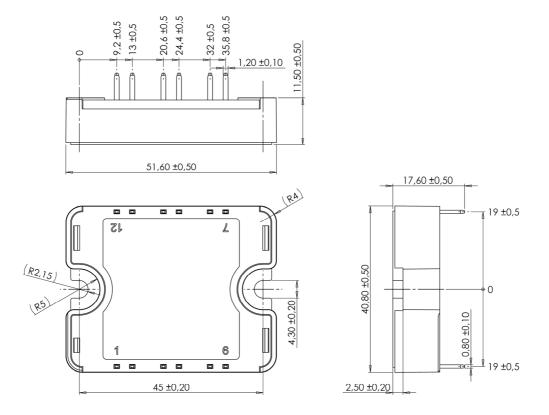
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

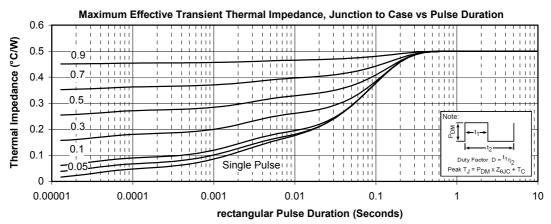
SP1 Package outline (dimensions in mm)

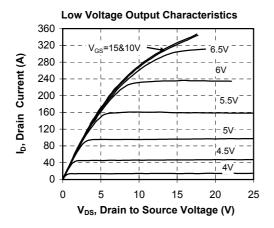


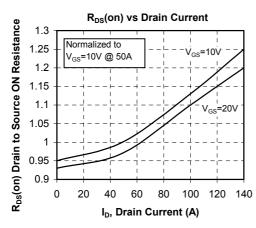
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

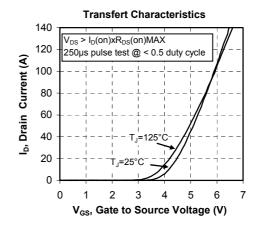


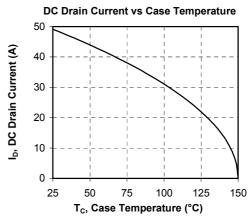
Typical IGBT Performance Curve



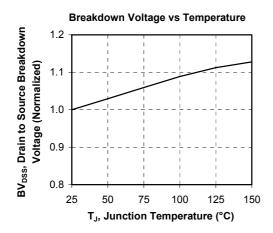


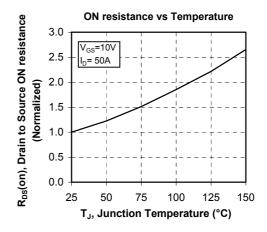


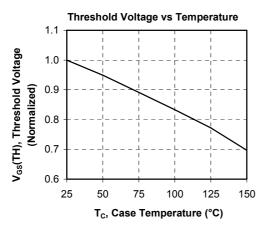


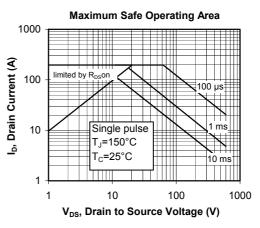


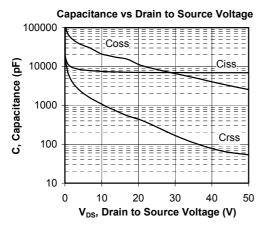


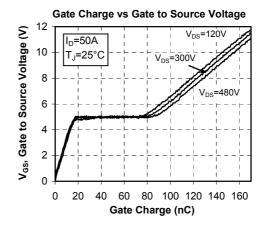




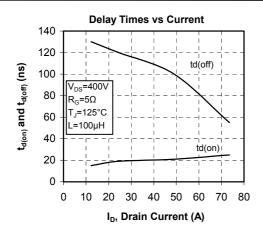


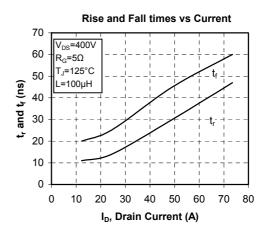


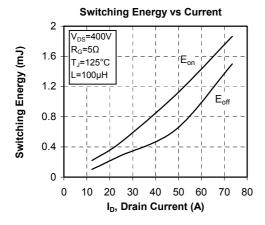


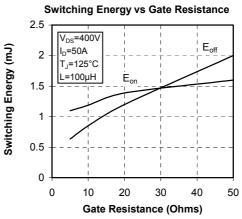


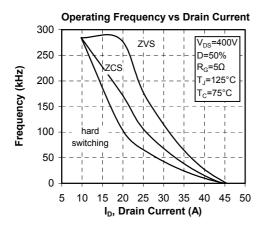


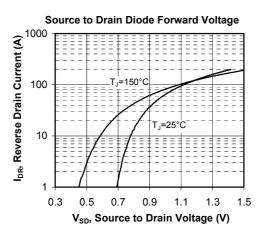


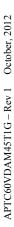






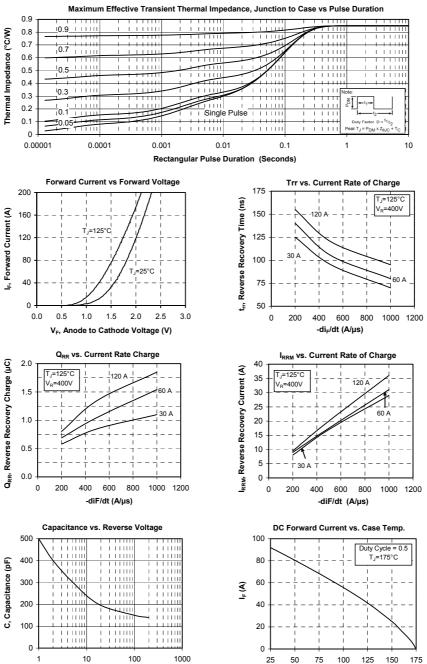








Typical chopper diode Performance Curve



"COOLMOSTM comprise a new family of transistors developed by Infineon Technologies AG. "COOLMOS" is a trademark of Infineon Technologies AG".

Case Temperature (°C)

V_R, Reverse Voltage (V)

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